#### OCXO3321AW02

Ultra-Low Power and High Stability OCXO

## **Features and Benefits**

Frequency range: 8MHz - 150MHz

Supply voltage: 3.3V/5.0V

Steady power consumption: 90mW Typ.

Output waveform: HCMOS/Sine

Frequency stability vs. operating temperature: ±2ppb (optional)

Aging: ±0.1ppb/day (optional)

Operating temperature: -40°C to +85°C

Size: 21.6x15.3x11.6mm

## **Typical Applications**

Portable Wireless Communications Mobile Test Equipment Beacons and Rescue Systems Battery Powered Applications

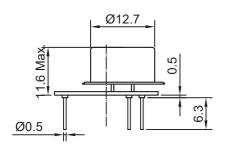
## **Description**

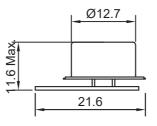
The OCXO3321AW02 is the ultra-low power, high stability, and fast warm-up OCXO. The frequency stability can less than ±2PPB from -40°C to +85°C. It can be widely used in the battery powered communication devices.

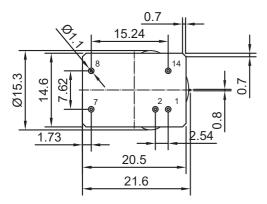
## **Mechanical Drawing & Pin Connections**

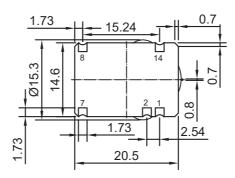
**Drawing No:** 

MD220024-1









Pin	Signal
1	Control voltage
2	Reference voltage
7	GND
8	Output
14	Supply voltage

Unit in mm 1mm = 0.0394 inches

We reserves the right to reduce the external dimensions without changing of connecting dimensions.



# Dynamic Engineers Inc.

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### OCXO3321AW02

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# **Specifications**

(	Oscillator	Sum	Condition		Value		Unit	Note
_	ecification	Sym	Condition	Min.	Тур.	Max.		
Operational Frequency		$f_0$		8		150	MHz	
Initial Tol		$(f-f_0)/f_0$	+25°C, V <sub>C</sub> =0.5*V <sub>ref</sub>		±0.1		ppm	
RF Outpo	ut							
	Level	L	V <sub>CC</sub> =5V V <sub>CC</sub> =3.3V	+7 +4			dBm	
Sine-	Load	R∟			50		Ohm	
wave	Harmonics Level					-25	dBc	
	Sub-harmonics level				None			
	H-Level Voltage	V <sub>H</sub>	Vcc=5V Vcc=3.3V	3.8 2.4			V	
HCMOS	L-Level Voltage	VL				0.4	V	
(TTL)	Load			10			Kohm	
( /				4=		15/5	pF	10/100MHz
	Duty Cycle			45		55	%	40/4000411-
Power St	Rise/Fall Time					10/3	ns	10/100MHz
Power 30	ирріу			4.75	5.0	5.25		
Voltage		Vcc		3.15	3.3	3.45	V	
Dower Co	noumntion		Warm-up	3110		1200	mW	10MHz, -40°C to
Power Co	onsumption		Steady state, +25°C		90		mW	+85°C
Warm-up	Time:	T <sub>up</sub>	At+25° C to $\Delta f/f=1e-8$ At+25° C to $\Delta f/f=1e-7$	30	120 60		S	ref. frequency after 15 min work.
Frequenc	cy Control							
Control V	oltage Range	Vc	V <sub>CC</sub> =5V Vcc=3.3V	0		4.2 2.8	V	
Tuning R	ange		Compliance with 10 years of aging	±0.3	±1.0		ppm	Positive slope
Referenc	e Voltage Output	V <sub>ref</sub>	V <sub>cc</sub> =5V Vcc=3.3V	4.0 2.7		4.3 3.1	V	
Frequenc	cy Stability		VCC-0.5V	2.1		5.1		
	emperature		ref 25°C	±1.0			ppb	See ordering code
Versus S	upply Voltage		Ref Vcc typ.		±2.0		ppb	0000
	G-Sensitivity		Worst direction, 0-1KHz vibration BW	±0.2	±1.0		ppb/G	
Retrace			24h work after 24h off			±10	ppb	10MHz
	Per day		After 30 days of	±0.1			ppb	See ordering
Aging	First Year		operation	±0.015			ppm	code
	•		@1Hz	-105/		-90/		
			@10Hz	-135		-120		
			W 10112	/-100		/-90		
SSB Phase Noise			@100Hz	-155		-145		
			<u> </u>	/-130		/-120		10MHz
			@1KHz	-165 /-155		-155 /-150	dBc/Hz	/100MHz
			@10KHz	-170		-165	-	Vcc=5V
				/-170		/-165		V 00-0 V
				1-110				
			@100KHz	-172 /-172		-165 /-165		

### OCXO3321AW02

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Environmental Conditions	
Operating temperature range	-40°C to +85°C (See ordering code)
Storage temperature range	-60°C to +85 °C
Power Voltage	-0.5V to Vcc +20%
Control Voltage	-0.5V to +6V
Airflow Velocity	0.5m/s max.
Humidity	Non-condensing 95%
Mechanical Shock	Per MIL-STD-202, 30G half sine pulse, 11ms
Vibration	Per MIL-STD-202, 10G swept sine 0 to 2000 Hz
Soldering Conditions	Hand solder only – not reflow compatible 260°C 10s (on pins)
Washing Conditions  Washing with water or alcohol based detergent allowed only with final enough drying stage	

## **Ordering Information**

Group Code

For example, OCXO33121AW02-100MHz-257111 denotes the OCXO has the following specifications:

Frequency 100MHz -10°C to +60°C ±10ppb 2ppb / 0.2ppm 3.3V ±10%

Temperature Range Stability Over Temperature Aging per day / year Supply Voltage Output **HCMOS** Package DIP

01	Temperature Range		
Code	Specification		
1	0°C to +50°C		
2	-10°C to +60°C		
3	0°C to +70°C		
4	-20°C to +70°C		
5	-30°C to +70°C		
6	-40°C to +85°C		
7	-55°C to +85°C		
8	-60°C to +85°C		

02	Stability Over Temperature			
Code	Specification	Available temperature range code		
		10MHz	100MHz	
1	±1.0 ppb	1 to 5	-	
2	±2.0 ppb	1 to 6	-	
3	±3.0 ppb	1 to 6	-	
4	±5.0 ppb	1 to 7	1	
5	±10 ppb	1 to 8	1 to 6	
6	±20 ppb	1 to 8	1 to 7	
7	±50 ppb	1 to 8	1 to 8	
8	±100 ppb	1 to 8	1 to 8	

03	Aging per day/year, ppb/ppm			
Code	Specifi	cation		
1	0.1/0.015*			
2	0.2/0.02	≤10MHz		
3	0.3/0.03			
4	0.5/0.05	≤20MHz		
5	1/0.1	≤40MHz		
6	1.5/0.15	≤50MHz		
7	2/0.2	≤120MHz		
8	3/0.3	≤120MHz		
9	5/0.5	≤150MHz		

04	Supply Voltage
Code	Specification
1	3.3V±5%
2	5.0V±5%

05	RF Output
Code	Specification
1	HCMOS
2	Sinewave

<sup>\*</sup>Only for temperature 1 to 5

06	Packaging
Code	Specification
1	DIP
2	SMD